

Vishay Siliconix

N-Channel 60 V (D-S) MOSFET

DESCRIPTION

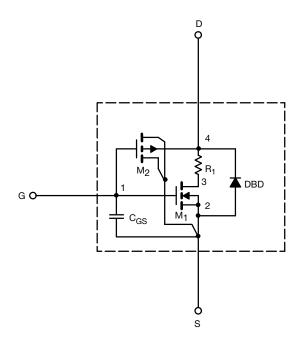
The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the - 55 °C to 125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{\rm gd}$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

SUBCIRCUIT MODEL SCHEMATIC



Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



SPICE Device Model Si7414DN

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SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.8	-	V
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	220	-	Α
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 10 \text{ V}, I_D = 8.7 \text{ A}$	0.021	0.021	Ω
		V _{GS} = 4.5 V, I _D = 7.3 A	0.030	0.030	
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 15 \text{ V}, I_D = 8.7 \text{ A}$	21	18	S
Diode Forward Voltage	V _{SD}	$I_S = 3.2 \text{ A}, V_{GS} = 0 \text{ V}$	0.74	0.75	V
Dynamic ^b					
Total Gate Charge	Qg	$V_{DS} = 30 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 8.7 \text{ A}$	15	16	nC
Gate-Source Charge	Q _{gs}		2.7	2.7	
Gate-Drain Charge	Q _{gd}		4.4	4.4	
Turn-On Delay Time	t _{d(on)}	$V_{DD} = 30 \text{ V}, R_L = 30 \Omega$ $I_D = 1 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 6 \Omega$ $I_F = 3.2 \text{ A}, dI/dt = 100 \text{ A/}\mu\text{s}$	13	15	ns
Rise Time	t _r		16	12	
Turn-Off Delay Time	t _{d(off)}		28	30	
Fall Time	t _f		42	12	
Source-Drain Reverse Recovery Time	t _{rr}		40	45	

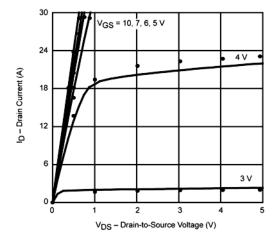
Notes

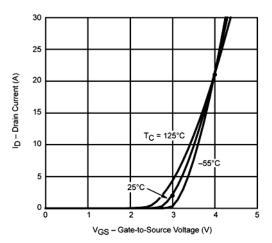
- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

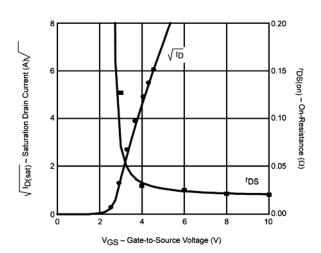
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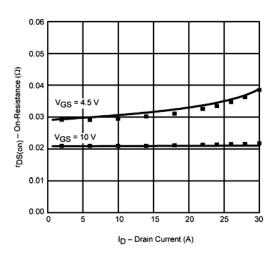
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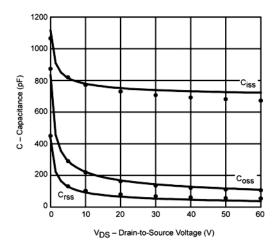
COMPARISON OF MODEL WITH MEASURED DATA ($T_J = 25$ °C, unless otherwise noted)

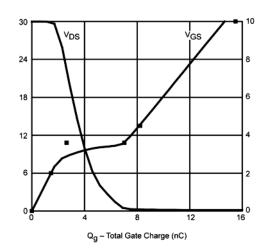












Note

• Dots and squares represent measured data.



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